



Slot-type Photomicrosensor with connector or pre-wired models (Non-modulated)*1

EE-SX672-WR 1M



Image

Slot-type Photomicrosensor with Cable, Dark-ON/Light-ON (selectable), Prewired models, 1 m

Туре	Grooved Type (T-shaped) (Slot center 7 mm)	
Luminous method	Non-modulated	
Sensing method	Through-beam type	
Sensing distance	Slot width: 5 mm	
Control output (Output type)	NPN open collector output	
Operation mode	Dark-ON/Light-ON (selectable)	
Connection method	Pre-wired models	

Ratings/Performance

As of March 13, 2024

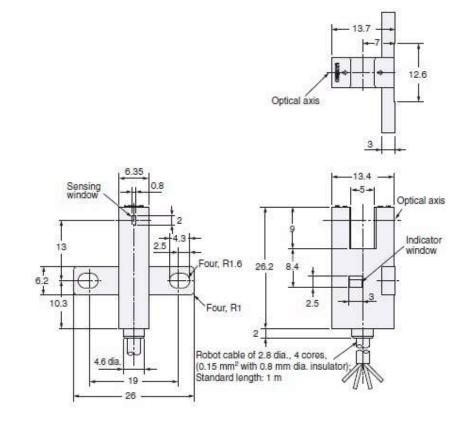
Туре		Grooved Type (T-shaped) (Slot center 7 mm)	
Luminous n	nethod	Non-modulated	
Sensing method		Through-beam type	
Sensing distance		Slot width: 5 mm	
Operation m	node	Dark-ON/Light-ON (selectable)	
Standard se	ensing object	Opaque, 2 x 0.8 mm min.	
Differential distance elements		0.025 mm max.	
Light source wavelength		Infrared LED (940 nm)	
Indicator		Light indicator (red)	
Power supply voltage		5 to 24 VDC ±10% ripple (p-p) 10 % max.	
Current consumption		35 mA	
	Output type	NPN open collector output	
Control output	Load power supply voltage	5 to 24 VDC	
	Load curren	100 mA max.	
	Residual voltage	at 100 mA load current: 0.8 V max. at 40 mA load current: 0.4 V max.	
Response frequency elements		1 kHz min. Average value: 3 kHz	
Illumination on the surface receiver		Fluorescent light: 1000 lx max.	

Ambient temperature	temperature Operating: -25 to 55 °C (with no freezing or condensation) Storage: -30 to 80 °C (with no freezing or condensation)	
Ambient humidity	Operating: 5 to 85 % (with no condensation) Storage: 5 to 95 % (with no condensation)	
Vibration resistance	Destruction: 20 to 2000 Hz, peak acceleration 100 m/s ² , 1.5-mm double amplitude 2 h each in X, Y, and Z directions (4 min periods)	
Shock resistance	Destruction: 500 m/s ² for 3 times each in X, Y, and Z directions	
Degree of protection	IP50	
Connection method	tion method Pre-wired models	
Cable length	length 1 m	
Weight	Package: Approx. 17.8 g	
Material Case: Polybutylene terephthalate (PBT) Emitter/Receiver Cover: Polycarbonate (PC)		

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Dimensions

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Terminal array

Terminal Arrangement

Brown	(1)	Vcc
Pink	(2)	L
Blue	(3)	GND (0 V)
Black	(4)	OUTPUT

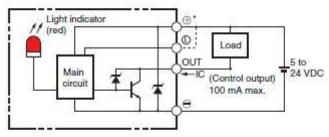
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I/O Circuit diagram

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Output circuit

EE-SX67□-WR



^{*}The terminal arrangement depends on the model. Check the dimensional diagrams.

Timing chart

Output configuration	Timing charts	Terminal connections	
Light-ON	Incident Interrupted Light indicator ON (red) OFF Output ON transistor OFF Load Operates (e.g., relay) Releases	Short-circuited between ① terminal and positive ① terminal	
Dark-ON	Incident Interrupted Light indicator ON (red) OFF Output ON transistor OFF Load Operates (e.g., relay) Releases	Open between © terminal and positive ⊕ terminal *1 *2	

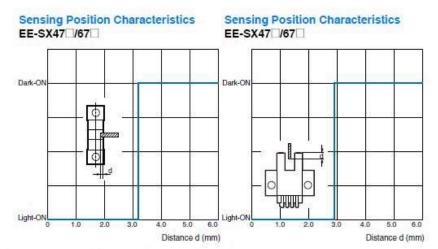
^{*1.} Do not connect the L terminal to 0 V when using dark-ON operation.

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Engineering data (Reference value)

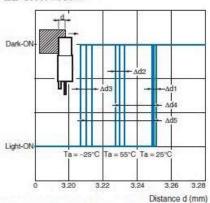
^{*2.} If you do not use the L terminal vio V when using dark-ON operation.
*2. If you do not use the L terminal wire ((2) pink) when you use a Connector with Cable for an EE-1006 or EE-1010-series Photomicrosensor, noise may affect the Photomicrosensor. To prevent the effects of noise, cut the unused L terminal wire at the base of the connector and wrap it with insulating tape to prevent it from coming in contact with other terminals.

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Repeated Sensing Position Characteristics

EE-SX47 /67



Vcc =12 V, No. of repetitions; 20, Δ d1 = 0.002 mm, Δ d2 = 0.004 mm, Δ d3 = 0.005 mm, Δ d4 = 0.02 mm,

 $\Delta d5 = 0.04 \, \text{mm}$

Note: The data applies to dark status. Operation may be affected by external light interference or light coming through the sensing object.

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